NSN 5961-01-107-0964

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emitter to base voltage, dc

View Online at https://aerobasegroup.com/nsn/5961-01-107-0964

Inclosure	Material:
Metal	
Overall L	ength:
0.210 incl	nes
Terminal	Length:
0.500 incl	nes
Overall D	iameter:
0.230 incl	nes
Internal (Configuration:
Junction of	contact
Joint Ele	ctronic Device Engineering Council/jedec/case Outline Designation:
To-72	
Mounting	J Method:
Terminal	
Terminal	Circle Diameter:
0.100 incl	nes
Features	Provided:
Hermetica	ally sealed case
Semicon	ductor Material:
Silicon	
Voltage F	Rating In Volts Per Characteristic:
15.0 colle	ector to base voltage, dc and 15.0 collector to emitter voltage, dc and 4.5
Current F	Rating Per Characteristic:
30.00 mill	iamperes source cutoff current
Power Ra	ating Per Characteristic:
200.0 mill	iwatts small-signal input power, common-collector preset
Maximun	n Operating Tempurature Per Measurement Point:
200.0 deg	rees celsius ambient air
Special F	eatures:
Junction p	pattern arrangement: pnp
Precious	Material And Location:
Terminals	gold
Precious	Material:
Gold	
Terminal	Type And Quantity:
4 uninsula	ated wire lead
Shelf Life	
N/a	
Unit Of N	leasure:
Demilitar	ization:
No	

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Fiig: A110a0

